EV2316-D-00A

3A, 19V, Constant-On-Time Step-Down Switcher Evaluation Board

DESCRIPTION

The EV2316-D-00A is used for demonstrating the performance of MP2316, a fully-integrated, high efficiency, synchronous step-down switch mode converter with the feathered 40uA quiescent current. MP2316 provides up to 3A continuous output current over a wide input supply range with constant-on-time control for fast loop response.

High power efficiency over a wide load range is achieved by scaling down the switching frequency at light load to reduce the switching related loss by constant on time control. Short circuit and thermal shutdown provides reliable, fault-tolerant operation.

MP2316 is available in 2mmx3mm 14-pin QFN package.

ELECTRICAL SPECIFICATION

Parameter	Symbol	Value	Units
Input Voltage	V_{IN}	4– 19	V
Output Voltage	V_{OUT}	1.2	V
Output Current	I_{OUT}	3	A

FEATURES

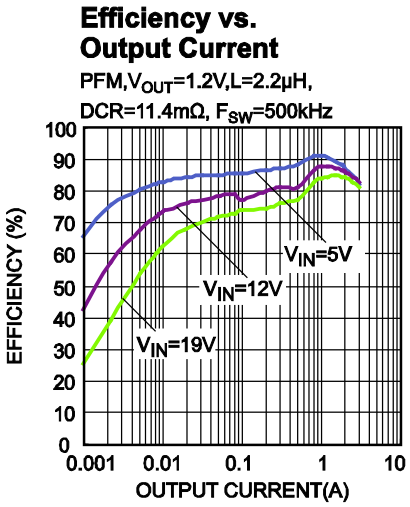
- Wide 4V to 19V Operating Input Range
- Up to 3A Output Current
- 40μA Quiescent Current
- 90mΩ /30mΩ High Side/ Low Side $R_{DS(ON)}$ for Internal Power MOSFETs
- PWM/PFM Mode Selectable
- Programmable Switching Frequency
- Power Good Indicator
- Cycle-by-Cycle Over Current Protection
- Short Circuit Protection with Hiccup Mode
- Thermal Shutdown
- Stable with Low ESR Ceramic Output Capacitors
- Programmable Soft-Start Time
- Available in QFN14 (2mmx3mm)Package

APPLICATIONS

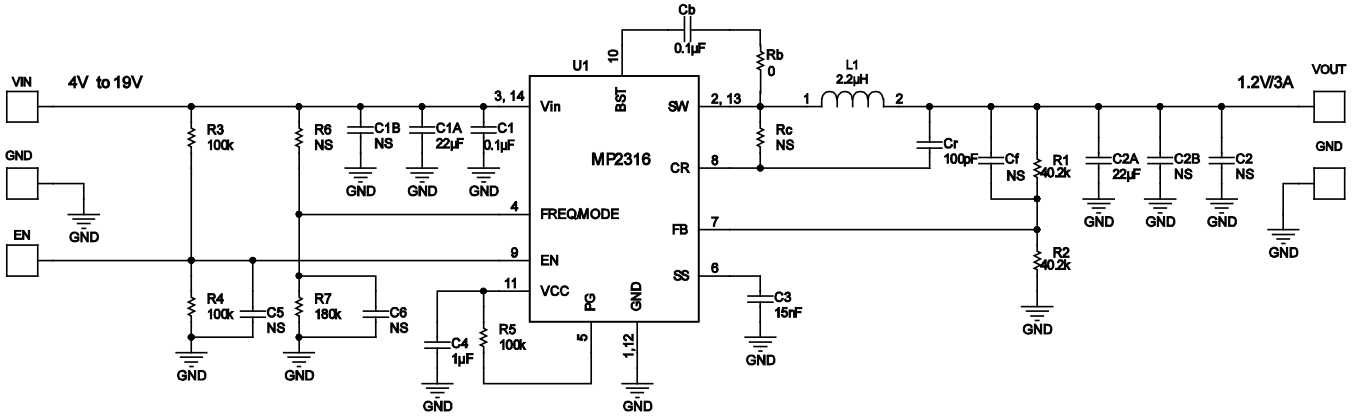
- Tablet PCs
- Solid State Drives
- Gaming
- Battery-operated Applications

EV2316-D-00A EVALUATION BOARD

Board Number	MPS IC Number
EV2316-D-00A	MP2316GD



EVALUATION BOARD SCHEMATIC



Note: Use R6 and not use R7 to set part work at force PWM Mode, Use R7 and not use R6 to set part work at Auto PFM/PWM Mode.

EV2316-D-00A BILL OF MATERIALS

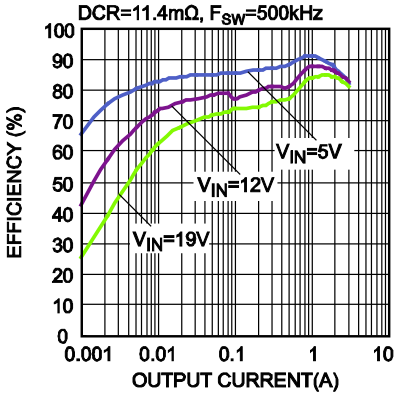
Qty	RefDes	Value	Description	Package	Manufacturer	Manufacturer P/N
2	R1,R2	40.2k	Film Res, 1%	0603	ROYAL	RL0603FR-0740K2L
3	R3, R4,R5	100k	Film Res, 1%	0603	ROYAL	RL0603FR-07100KL
0	R6,Rc	NS				
1	R7	180k	Film Res, 1%	0603	ROYAL	RL0603FR-07180KL
1	Rb	0Ω	Film Res, 1%	0603	Yageo	RC0603FR-070RL
1	C1	0.1µF	Ceramic Cap,25V,X7R	0603	Murata	GRM188R71E104KA01D
0	C2, C5, C6,Cf, C1B, C2B	NS				
1	Cb	0.1µF	Ceramic Cap, 16V, X7R	0603	Murata	GRM188R71C104KA01D
1	C3	15nF	Ceramic Cap, 50V, X7R	0603	TDK	C1608X7R1H153K
1	C4	1µF	Ceramic Cap,16V, X7R	0603	Murata	GRM188R71C105KA12D
1	Cr	100pF	Ceramic Cap, 50V, C0G	0603	Murata	GRM1885C1H101JA01D
1	C1A	22µF	Ceramic Cap,25V,X7R	1206	Murata	GRM31ER71E226KE15L
1	C2A	22µF	Ceramic Cap,10V,X7R	1206	Murata	GRM31CR71A226KE15L
1	L1	2.2µH	Inductor, DCR=11.4mΩ, Isat=13A	SMD	Wurth	744311220
1	U1	MP2316GD	Synchronous Step-down Converter	QFN14(2mmX3mm)	MPS	MP2316GD

EVB TEST RESULTS

Performance waveforms are tested on the evaluation board.
V_{IN}=12V, V_{OUT}=1.2V, L=2.2uH, T_A=25°C, unless otherwise noted.

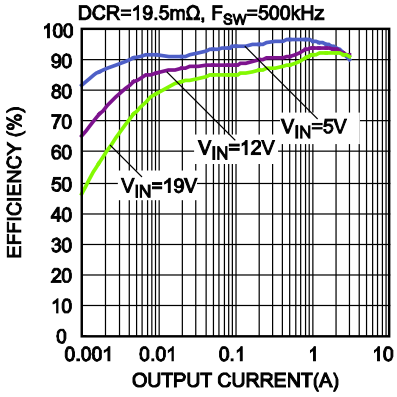
Efficiency vs. Output Current

PFM,V_{OUT}=1.2V,L=2.2µH,
DCR=11.4mΩ, F_{SW}=500kHz



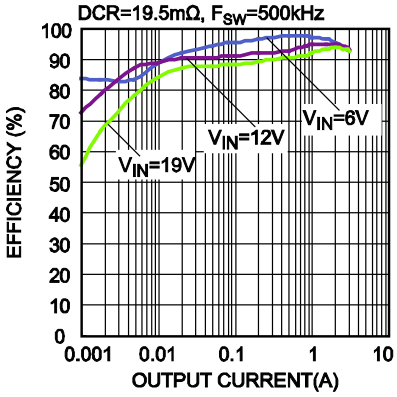
Efficiency vs. Output Current

PFM,V_{OUT}=3.3V,L=4.7µH,
DCR=19.5mΩ, F_{SW}=500kHz



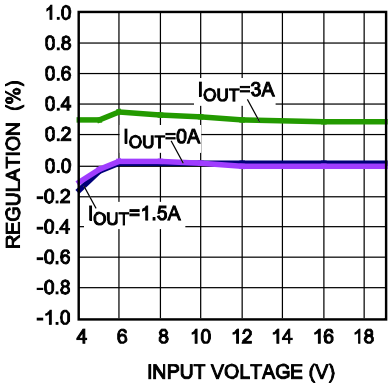
Efficiency vs. Output Current

PFM,V_{OUT}=5V,L=4.7µH,
DCR=19.5mΩ, F_{SW}=500kHz



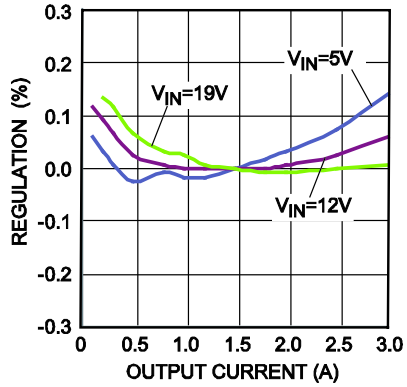
Line Regulation

V_{IN}=4V to 19V



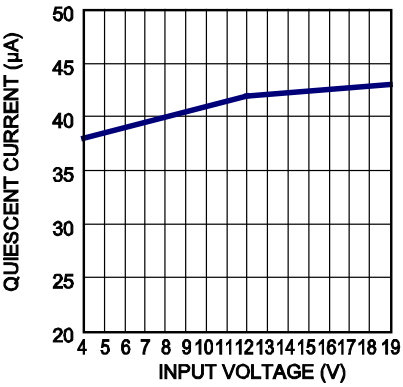
Load Regulation

V_{IN}=4V to 19V



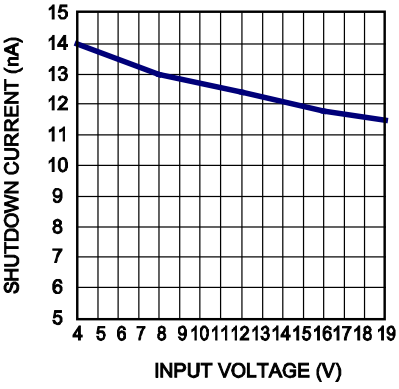
Quiescent Current vs. Input Voltage

V_{IN}=4 to 19V,V_{FB}=0.7V

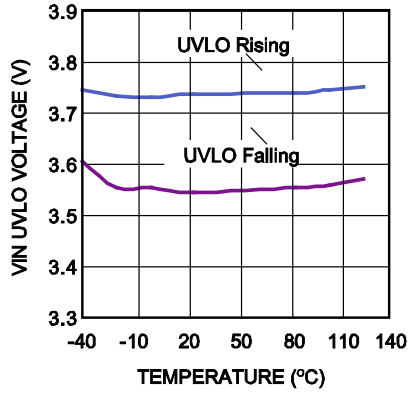


Shutdown Current vs. Supply voltage

V_{IN}=4 to19V,V_{EN}=0V

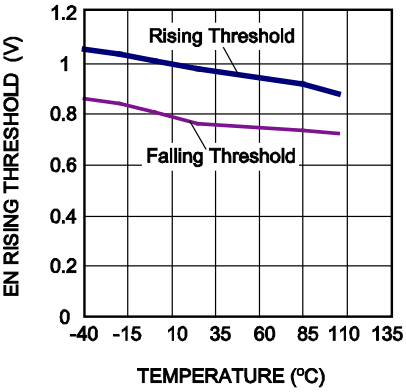


Vin UVLO vs. Temperature



EN Rising Threshold vs. Temperature

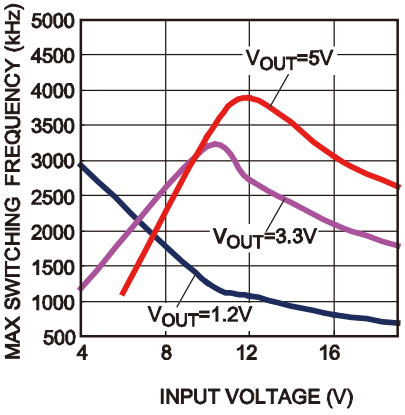
V_{IN}=12V



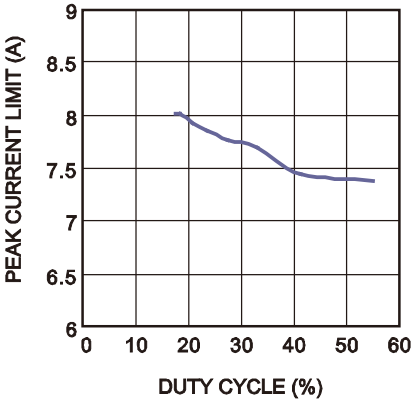
EVB TEST RESULTS *(continued)*

Performance waveforms are tested on the evaluation board.
V_{IN}=12V, V_{OUT}=1.2V, L=2.2uH, T_A=25°C, unless otherwise noted.

Max Frequency vs. Input Voltage

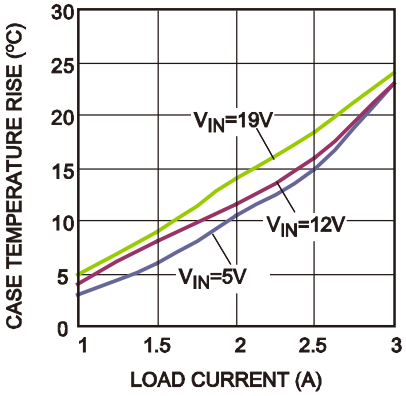


Peak Current Limit vs. Duty Cycle



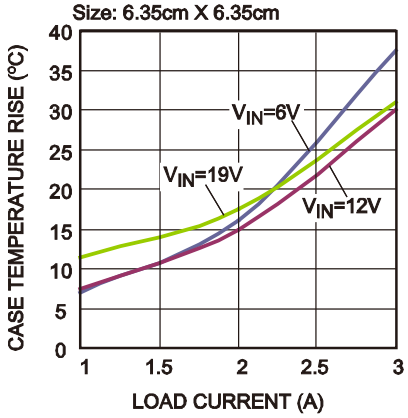
Case Temperature Rise vs. I_{OUT}

V_{OUT}=1.2V, I_{OUT}=1A to 3A, 4 Layers PCB, Size: 6.35cm X 6.35cm



Case Temperature Rise vs. I_{OUT}

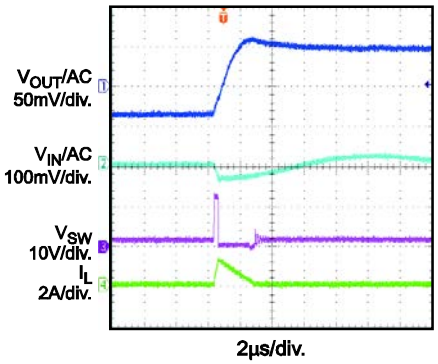
V_{OUT}=5V, I_{OUT}=1A to 3A, 4 Layers PCB, Size: 6.35cm X 6.35cm



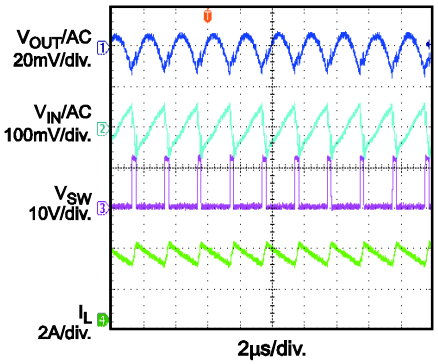
EVB TEST RESULTS *(continued)*

Performance waveforms are tested on the evaluation board.
V_{IN}=12V, V_{OUT}=1.2V, L=2.2uH, T_A=25°C, unless otherwise noted.

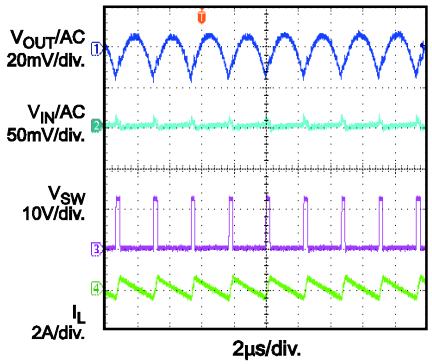
Input/Output Ripple
PFM, I_{OUT}=0A



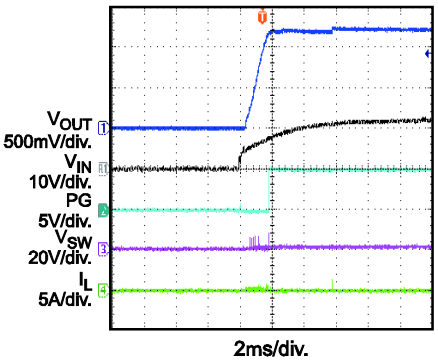
Input/Output Ripple
I_{OUT} = 3A



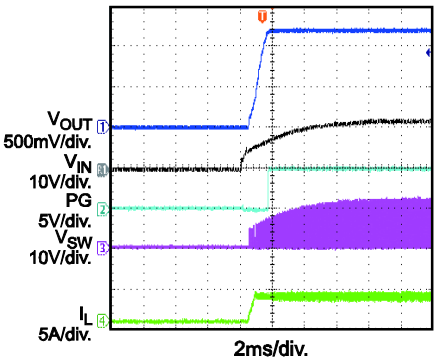
Input/Output Ripple
Force PWM, I_{OUT}=0A



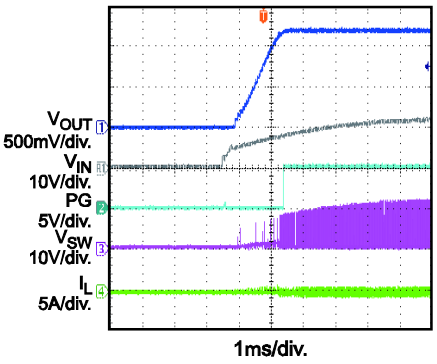
Startup through V_{IN}
PFM, I_{OUT}=0A



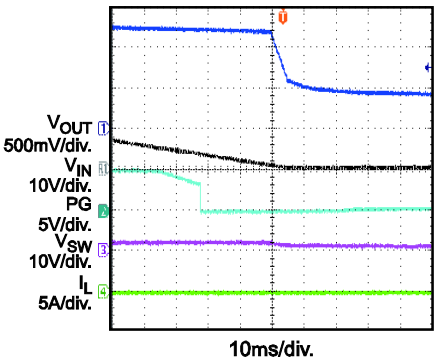
Startup through V_{IN}
I_{OUT} = 3A



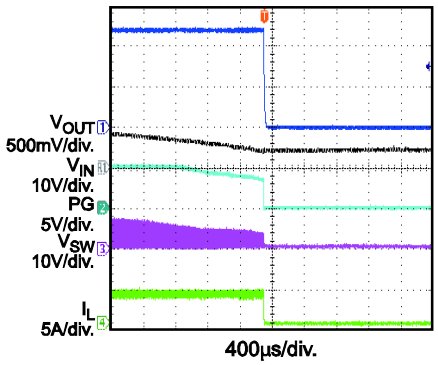
Startup through V_{IN}
Force PWM, I_{OUT}=0A



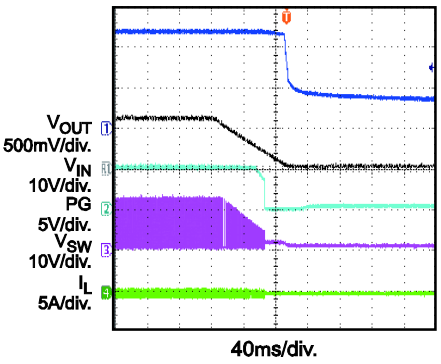
Shutdown through V_{IN}
PFM, I_{OUT}=0A



Shutdown through V_{IN}
I_{OUT} = 3A



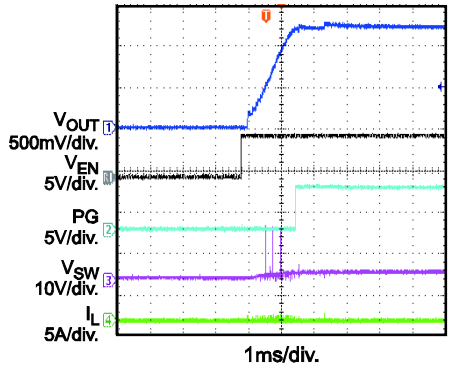
Shutdown through V_{IN}
Force PWM, I_{OUT}=0A



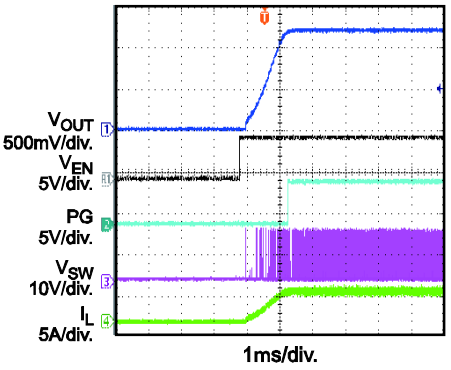
EVB TEST RESULTS *(continued)*

Performance waveforms are tested on the evaluation board.
V_{IN}=12V, V_{OUT}=1.2V, L=2.2uH, T_A=25°C, unless otherwise noted.

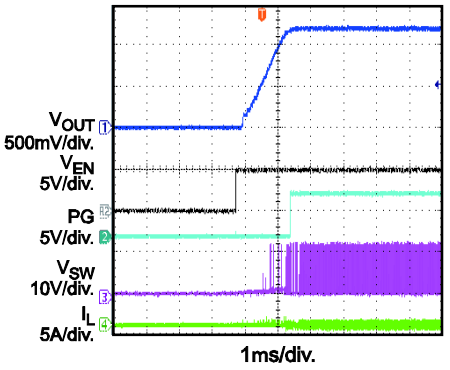
Startup through EN
PFM, I_{OUT}=0A



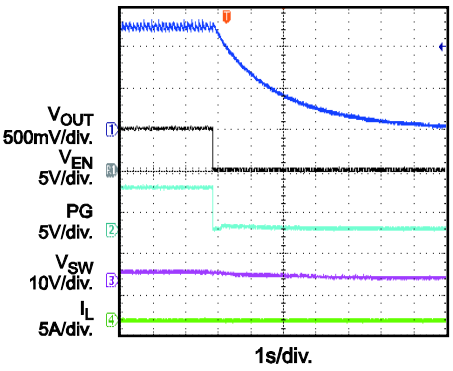
Startup through EN
I_{OUT} = 3A



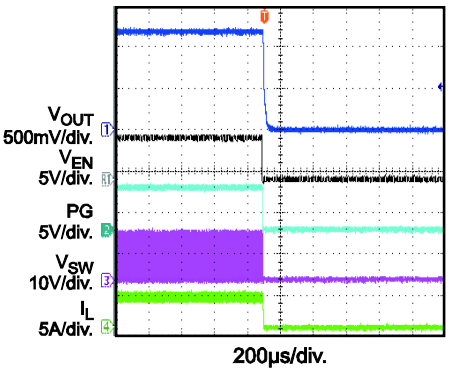
Startup through EN
Force PWM,, I_{OUT}=0A



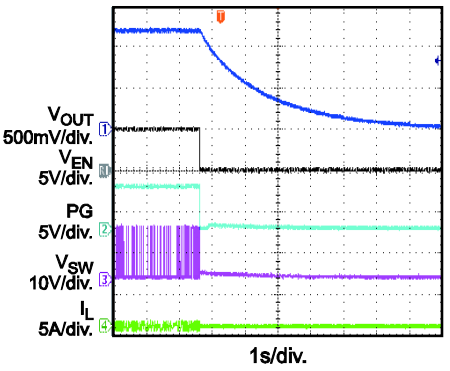
Shutdown through EN
PFM, I_{OUT}=0A



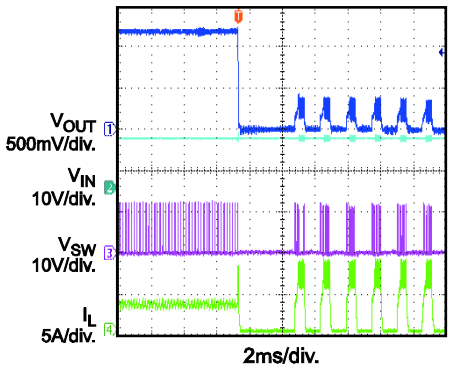
Shutdown through EN
I_{OUT} = 3A



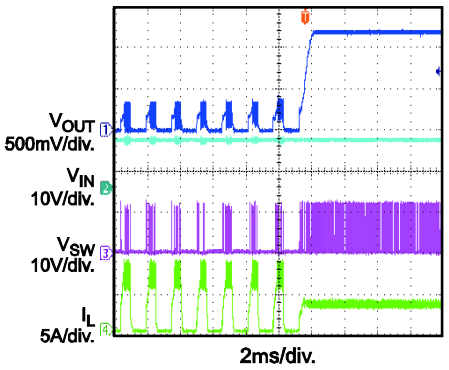
Shutdown through EN
Force PWM,, I_{OUT}=0A



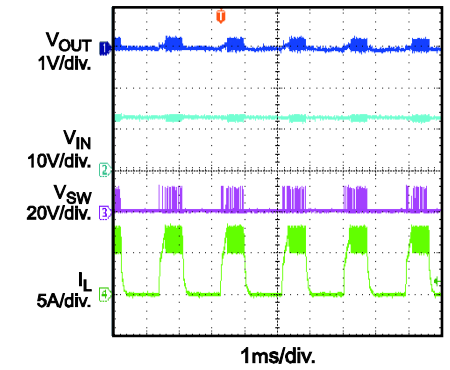
Short Circuit Entry
I_{OUT}=3A



Short Circuit Recovery
I_{OUT} = 3A



Short Circuit Steady
I_{OUT} = 3A

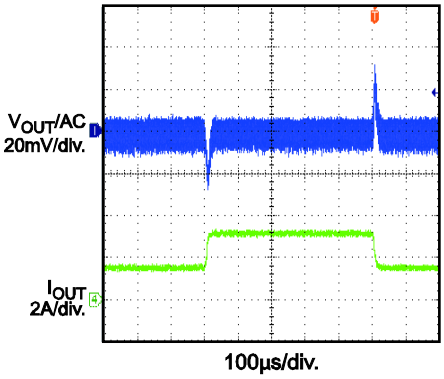


EVB TEST RESULTS *(continued)*

Performance waveforms are tested on the evaluation board.
V_{IN}=12V, V_{OUT}=1.2V, L=2.2uH, T_A=25°C, unless otherwise noted.

Load Transient

I_{OUT}=1.5A to 3A, 250mA/µs



PRINTED CIRCUIT BOARD LAYOUT

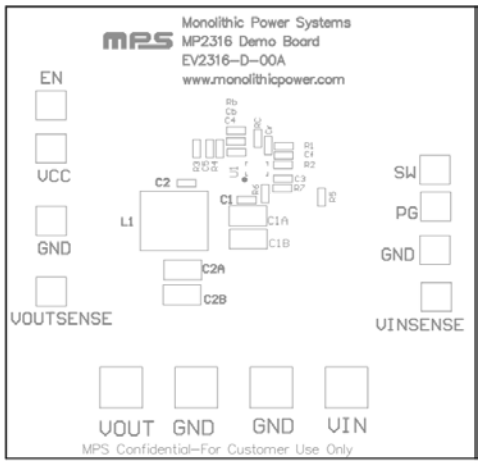


Figure 1—Top Silk Layer

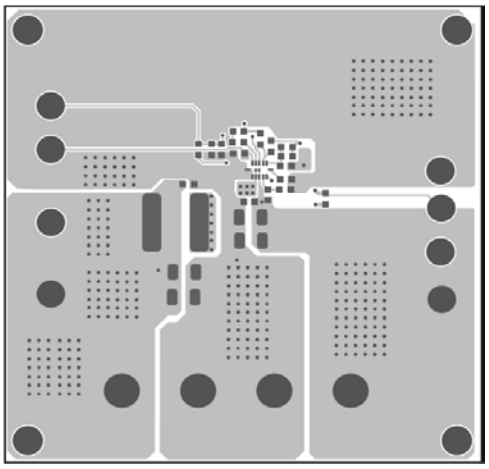


Figure 2—Top Layer

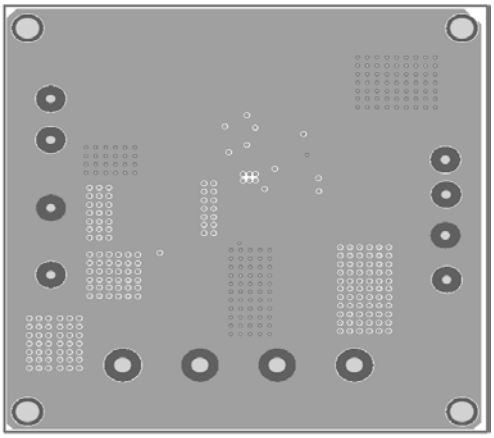


Figure 3— Inner 1 Layer

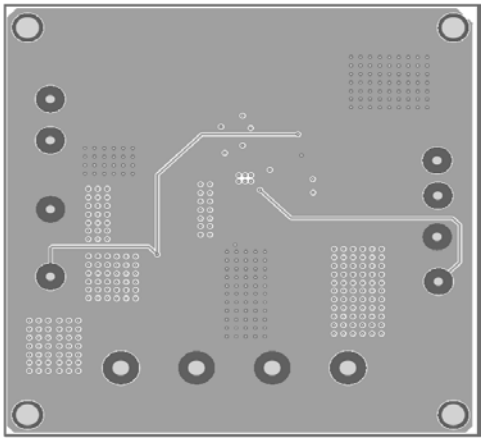


Figure 4— Inner 2 Layer

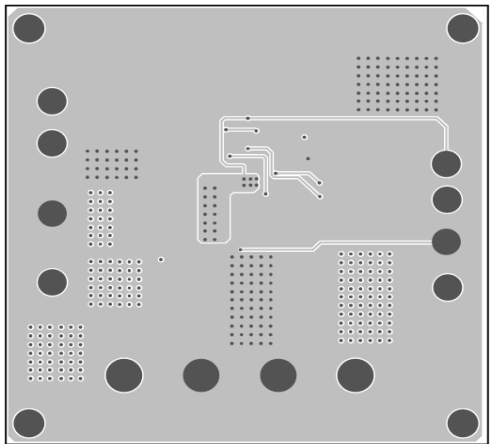


Figure 5— Bottom Layer